

## Electronic Patent Application Fee Transmittal

<b>Application Number:</b>	10675575			
<b>Filing Date:</b>	30-Sep-2003			
<b>Title of Invention:</b>	In-situ removal of surface impurities prior to arsenic-doped polysilicon deposition in the fabrication of a heterojunction bipolar transistor			
First Named Inventor/Applicant Name:	Leonard J. Olmer			
<b>Filer:</b>	Ronald J. Corbett/Elizabeth Schumacher			
<b>Attorney Docket Number:</b>	BEVERS 2-3-16-20			
Filed as Large Entity				
<b>Utility      Filing Fees</b>				
<b>Description</b>	<b>Fee Code</b>	<b>Quantity</b>	<b>Amount</b>	<b>Sub-Total in USD(\$)</b>
<b>Basic Filing:</b>				
<b>Pages:</b>				
<b>Claims:</b>				
<b>Miscellaneous-Filing:</b>				
<b>Petition:</b>				
<b>Patent-Appeals-and-Interference:</b>				
Post-Allowance-and-Post-Issuance:				
<b>Extension-of-Time:</b>				

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Miscellaneous:				
Request for continued examination	1801	1	810	810
Total in USD (\$)				810